

MBRS10H100CT - MBRS10H200CT

10.0 AMPS, Surface Mount Schottky Barrier **Rectifiers** Switchmode Power Rectifiers

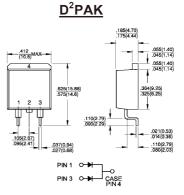


Features

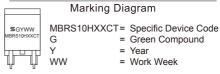
- Plastic material used carries Underwriters Laboratory Classifications 94V-0
- ♦ Metal silicon junction, majority carrier conduction
- ÷ Low power loss, high efficiency
- ¢ High current capability, low forward voltage drop Ŷ High surge capability
- ♦ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ¢ Guardring for overvoltage protection
- ⊹ High temperature soldering guaranteed: 260°C/10 seconds,0.25"(6.35mm) from case
- Ŷ Green compound with suffix "G" on packing code & prefix "G" on datecode.

Mechanical Data

- Cases: D2PAK molded plastic ♦
- Terminals: Pure tin plated, lead free, solderable per ♦ MIL-STD-750. Method 2026
- \diamond Polarity: As marked
- ♦ Mounting position: Any
- Ŷ Mounting torque: 5 in. - Ibs. max
- \diamond Weight: 0.08 ounce, 2.24 grams



Dimensions in inches and (millimeters)



Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%

Type Number	Symbol	MBRS 10H100CT	MBRS 10H150CT	MBRS 10H200CT	Units
Maximum Recurrent Peak Reverse Voltage	Vrrm	100	150	200	V
Maximum RMS Voltage	VRMS	70	105	140	V
Maximum DC Blocking Voltage	VDC	100	150	200	V
Maximum Average Forward Rectified Current at T _c =133°C	(av)	10			А
Peak Repetitive Forward Current (Rated V _R , Square Wave, 20KHz) at Tc=133°C	FRM	10			А
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	Ігѕм	120			A
Peak Repetitive Reverse Surge Current (Note 1)	RRM	1	1.0 0.5		А
Maximum Instantaneous Forward Voltage at (Note 2) I _F = 5A, Tc=25°C I _F = 5A, Tc=125°C I _F =10A, Tc=25°C I _F =10A, Tc=125°C	VF	0.85 0.75 0.95 0.85	0.88 0.75 0.97 0.85		V
Maximum Instantaneous Reverse Current at Rated DC Blocking Voltage @Tc=25 °C @ Tc=125 °C	IR	5.0 1.0		uA mA	
Voltage Rate of Change, (Rated V _R)	dV/dt	10,000			V/uS
RMS Isolation Voltage (t=1.0 second, R.H. ≦30%, T _A =25 °C) (Note 4) (Note 5) (Note 6)	Viso	4500 3500 1500			V
Typical Thermal Resistance Per Leg (Note3)	Rejc	3.5			°C/W
Operating Junction Temperature Range	TJ	-65 to +175			°C
Storage Temperature Range	TSTG	-65 to +175			°C

Notes

1. 2.0 us Pulse Width, f=1.0 KHz 2. Pulse Test: 300us Pulse Width, 1% Duty Cycle

3. Thermal Resistance from Junction to Case Per Leg.

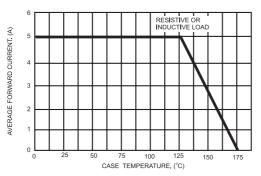
4. Clip Mounting (on case), where lead does not overlap heatsink with 0.110" offset.

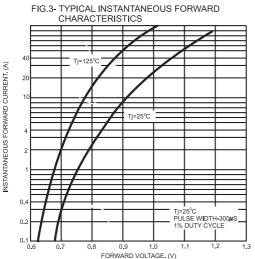
5. Clip mounting (on case), where leads do overlap heatsink.

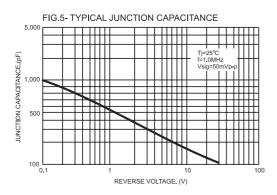
6. Screw mounting with 4-40 screw, where washer diameter is \leq 4.9 mm (0.19")

RATINGS AND CHARACTERISTIC CURVES (MBRS10H100CT - MBRS10H200CT)









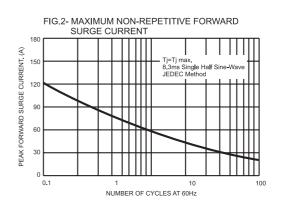


FIG.4- TYPICAL REVERSE CHARACTERISTICS

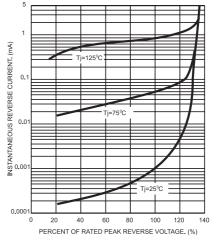


FIG.6- TYPICAL TRANSIENT THERMAL CHARACTERISTICS PER LEG

